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Preparation and structural characterization of trimethylsilylsubstituted germylzinc halides, $(Me_3Si)_3GeZnX$ (X = Cl, Br, and I) and silylzinc chloride, R(Me_3Si)_2SiZnCl (R = SiMe_3 and Ph)

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Abstract

The trimethylsilyl-substituted germylzinc halides, $(Me_3Si)_3GeZnX$ (X = Cl, Br, and I), and silylzinc chlorides, $R(Me_3Si)_2SiZnCl$ (R = SiMe₃, Ph), have been prepared and their molecular structures have been full determined by spectroscopic and single-crystal X-ray diffraction methods. The germylzinc halides and silylzinc chlorides have dimeric structures consisting of two μ -halogen atoms. The reactivity of germylzinc chloride with substrates is also examined.

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Keywords: Germylzinc halides; Silylzinc chlorides; Structure; X-ray diffraction; Reactivity

1. Introduction

Organozinc compounds are useful reagents not only in organic synthesis but also in organometallic chemistry [1]. The well-known Frankland and Reformatsky zinc alkylation, and Simmons-Smith reaction proceed via organozincs assumed as key intermediates. Despite the large number of reports on organozinc reagents, far less attention has been devoted to silvl- or germyl-substituted zinc compounds. Up to now, four bis(silyl)zinc derivatives { $(t-Bu_3Si)_2Zn$ [2a], [$(Me_3Si)_3Si]_2Zn$ [2b], (Me₃Si)₂Zn [2c] and (Ph₃Si)₂Zn [2d]} and two silylzinc halides $\{(t-Bu_3Si)ZnCl [2a] \text{ and } (t-Bu_3Si)ZnBr [2a]\}$ have been prepared and only three X-ray crystal structures of (t-Bu₃Si)₂Zn, [(Me₃Si)₃Si]₂Zn, and (t-Bu₃Si)ZnBr have been determined. Although a few example of bis(germyl)zinc, (Ph₃Ge)₂Zn and (Et₃-Ge)₂Zn, are known [3a-c], no solid state structure or few reactivities of bis(germyl)zinc derivatives have been reported. Furthermore, the Reformatsky-type germylzinc halides R_3GeZnX (X = halogen) have never been

isolated and characterized. In this report we describe the first successful isolation and structural characterization of tris(trimethylsilyl)germylzinc halides, (Me₃-Si)₃GeZnX (X = Cl, **1a**; Br, **1b**; I, **1c**) and tris(trimethyl-silyl)silylzinc chloride, (Me₃Si)₃SiZnCl (**2a**) and bis(trimethylsilyl)phenylsilylzinc chloride, Ph(Me₃-Si)₂SiZnCl (**2b**). Some reactions of the germylzinc chloride **1a** with substrates are also examined.

2. Results and discussion

2.1. Synthesis of tris(trimethylsilyl)germylzinc halides, $(Me_3Si)_3GeZnX$ (X = Cl, Br and I)

The treatment of zinc chloride $(ZnCl_2)$ with one molar equivalent of tris(trimethylsilyl)germyllithium solvated tetrahydrofuran (THF), $(Me_3Si)_3GeLi$ (thf)₃ [4], in diethyl ether at room temperature for 3 h afforded colorless crystals with a composition of $(Me_3Si)_3GeZnCl$ (thf) (1a) in 86% isolated yield. ¹H-, ¹³C- and ²⁹Si-NMR examination of a C₆D₆ solution of the colorless crystals 1a revealed a single signal assigned to the trimethylsilyl group (Me₃Si), and one THF molecule was included for a molecule 1a based on the ¹H- and ¹³C-NMR data.

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 $(Me_3Si)_3GeLi(thf)_3 + ZnX_2(excess)$

$$\rightarrow$$
 (Me₃Si)₃GeZnX(thf)₃

where X = Cl (1a), 86%; Br (1b), 71%; I (1c), 86%

The $(Me_3Si)_3GeLi$ $(thf)_3$ reacted with one molar equivalent of zinc bromide $(ZnBr_2)$ and zinc iodide (ZnI_2) in THF under similar conditions to give the corresponding germylzinc halides, $(Me_3Si)_3GeZnBr$ (thf) (1b) and $(Me_3Si)_3GeZnI$ (thf) (1c), in 71 and 86% isolated yields, respectively. The germylzinc bromide and -iodide coordinated one THF, 1b and 1c, were also confirmed by ¹H-, ¹³C- and ²⁹Si-NMR spectra.

The germylzinc chloride **1a** could be recrystallized from pentane at -20 °C as colorless needles flammable in air. The air-sensitive germylzinc bromide, **1b** and -iodide, **1c** could also be recrystallized from pentane at -20 °C as colorless needles flammable in air. The molecular structures of **1a**-**c** were unequivocally confirmed by X-ray diffraction analysis. The germylzinc halides, **1a**-**c** are dimeric structures consisting of two μ halogen atoms in the solid states. The molecular structures of **1a**-**c** have crystallographic inversion center as Figs. 1–3. In **1a**-**c** no interaction between the dimer and another dimer was observed.

The selected bond lengths and bond angles of 1a-c are summarized in Table 1. Crystallographic data of 1a-c are summarized in Table 4 in experimental section. The two zinc and two halogen atoms constitute a planar four-membered ring. For 1c, there are four independent molecules in the unit cell, and not a significant difference is found in one another. The two Zn-X distances of the four-membered ring in 1a-c are 2.356(11) and 2.400(2)

Å, 2.547(2) and 2.498(1) Å, and 2.710(2) and 2.727(2) Å, respectively. The X–Zn–X bond angles of 1a-c are in order 1a (92.75(4)°) < 1b (94.93(3)°) < 1c (98.81(3)°). On the other hand, the Zn–X–Zn bond angles for 1a-c are inversely in order 1c (81.49(4)°) < 1b (85.07(3)°) < 1a (87.25(4)°). The zinc atom of 1a-c is solvated by coordiantion to an oxygen atom of a THF molecule with a Zn–O distance of 2.097(4), 2.092(7), and 2.105(7) Å, respectively, and has a distorted tetrahedral configuration. The Ge–Zn bond length of 1a-c is within the range of 2.37–2.39 Å. The Si–Ge–Zn angle of 109.03(av.)–109.98(av.) and the Ge–Si bond length of 2.370–2.372Å are normal values.

Synthesis of tris(trimethylsilyl)silylzinc chloride, (Me₃Si)₃SiZnCl and bis(trimethylsilyl)phenylsilylzinc chloride, Ph(Me₃Si)₂SiZnCl. The ZnCl₂ reacted with one molar equivalent of tris(trimethylsilyl)silyllithium solvated THF, (Me₃Si)₃SiLi (thf)₃ [5] in THF at room temperature for 3 h to afford colorless crystals with a composition of (Me₃Si)₃SiZnCl (thf) (**2a**) in 81% isolated yield. The colorless crystals **2a** were identified with NMR (¹H-, ¹³C- and ²⁹Si-NMR) spectra, which displayed a single signal assigned to the Me₃Si group, and one THF molecule.

$$\frac{R(Me_{3}Si)_{2}SiLi(thf)_{3} + ZnCl_{2}(excess)}{\underset{r.t., THF}{\longrightarrow}} R(Me_{3}Si)_{2}SiZnCl(thf)_{3}$$

where $X = SiMe_3$ (2a), 81%; Ph (2b), 65%

The Ph(Me₃Si)₂SiLi (thf)₃ reacted with one molar equivalent of $ZnCl_2$ in THF under similar conditions to give the corresponding silyllzinc chloride, Ph(Me₃-Si)₂SiZnCl (thf) (**2b**) in 65% isolated yield. Bis(Tri-



Fig. 1. An ORTEP representation of the dimeric structure of 1a (hydrogen atoms are omitted for clarity).



Fig. 2. An ORTEP representation of the dimeric structure of 1b (hydrogen atoms are omitted for clarity).

methylsilyl)phenylsilane, $Ph(Me_3Si)_2SiH$ was also formed as a minor product in the reaction of $Ph(Me_3-Si)_2SiLi$ (thf)₃ with ZnCl₂. The silylzinc chloride coordinated one THF, **2b** were also established by ¹H-, ¹³C- and ²⁹Si-NMR spectra.

The silulizing chlorides, **2a** and **2b**, could be recrystallized from pentane at -20 °C as colorless crystals flammable in air. The molecular structures of 2a and 2b were fully established by X-ray diffraction analysis, as shown in Figs. 4 and 5. The silylzinc chlorides 2a and 2b are dimeric consisting of two μ -chlorine atoms as like as the germylzinc halides in the solid states. No interaction between the dimer and another dimer in these silylzinc chlorides was observed. The selected bond lengths and



Fig. 3. An ORTEP representation of the dimeric structure of 1c (hydrogen atoms are omitted for clarity).

Table 1 The selected bond lengths (Å) and bond angles (°) of $(Me_3Si)_3GeZnX$ (X = Cl, Br and I)

	1a (X = Cl)	$\mathbf{1b} \ (\mathbf{X} = \mathbf{Br})$	1c (X = I)	
Bond lengths				
Zn-X	2.356(1)	2.547(2)	2.710(2)	
	2.400(2)	2.498(1)	2.727(2)	
Ge-Zn	2.377(1)	2.383(2)	2.387(2)	
Zn–O	2.097(4)	2.092(7)	2.105(7)	
Bond angles				
X-Zn-X	92.75(4)	94.93(3)	98.81(3)	
Zn-X-Zn	87.25(4)	85.07(3)	81.49(4)	
Si-Ge-Si	109.89(av.)	109.60(av.)	108.93(av.)	

bond angles of **2a** and **2b** are summarized in Table 2. Crystallographic data of **2a** and **2b** are also summarized in Table 4 in Section 3.

The two zinc and two chlorine atoms in **2a** and **2b** constitute a planar four-membered ring with Zn-Cl distances of 2.3580(8) and 2.3982(8) Å, and 2.3853(14) and 2.4019(13) Å, respectively. The Cl-Zn-Cl bond angles of **2a** and **2b** are 92.62(13) and 91.49(4)°, respectively. The zinc atoms of **2a** and **2b** are solvated by coordiantion to an oxygen atom of a THF molecule with a Zn-O distance of 2.095(2) and 2.092(3) Å, respectively. The zinc atoms in these silylzinc chlorides have distorted tetrahedral configurations. The Si-Zn bond lengths of 2.3537(9) Å (**2a**) and 2.3652(12) Å (**2b**). The Si-Si-Zn angle of 108.97(av.)° (**2a**), 110.96(av.)° (**2b**), and the Si-Si bond length of 2.337(av.) Å (**2a**) and 2.347(av.) Å (**2b**) [2a] are quite normal.

Several reports on organozinc halides using highly sterically hindered silicon conpounds have been reported. The preparaton and structural characterization of (PhMe₂Si)₃CZnCl have been examined by Eaborn and co-workers [6]. The zinc in the crystal was present as the dimer [(PhMe₂Si)₃CZn(μ -Cl)₂ZnC(SiMe₂Ph)₃], with the zinc three-coordinate in a planar environment and the chloride bridged sligthly unsymmetrical. Wiberg and co-workers have reported the preparation of *t*-Bu₃SiZnCl and *t*-Bu₃SiZnBr by reactions of (*t*-Bu₃Si)₂Zn with BiCl₃ and BBr₃, respectively. Structure of *t*-Bu₃SiZnBr were tetramer with a regular cubic by Xray diffraction analysis [2a].

2.2. Reactions of germylzinc chloride

The reactions of **1a** with some electrophiles in diethyl ether under argon atmosphere in Schlenk tube were examined at room temperature. The hydrolysis of **1a** with deoxygenated water in diethyl ether under argon atmosphere proceeded extremely slow to give tris(trimethylsilyl)germane, $(Me_3Si)_3GeH$ in only 43% yield after 7 days of stirring. The addition of hydrochloric acid of **1a** for 2 h under argon atmosphere promoted the hydrolysis reaction up to 95% yield. The germylzinc chloride **1a** reacted slowly with Me₃SiCl for 4 days under argon atmosphere gave tetrakis(trimethylsilyl)germane, $(Me_3Si)_4Ge$ in 17% yield. Unreacted **1a** was recovered as $(Me_3Si)_3GeH$ after hydrolysis with water in 83% yield. The reaction of **1a** with I₂ did not proceed at room temperature for 4 days. Unreacted **1a** was



Fig. 4. An ORTEP representation of the dimeric structure of 2a (hydrogen atoms are omitted for clarity).



Fig. 5. An ORTEP representation of the dimeric structure of 2b (hydrogen atoms are omitted for clarity).

Table 2 The selected bond lengths (Å) and bond angles (°) of $R(Me_3Si)_2SiZnCl$ ($R = SiMe_3$ and Ph)

	$2a (R = SiMe_3)$	2b (R = Ph)	
Bond lengths			
Zn-Cl	2.3580(8)	2.3583(14)	
	2.3980(8)	2.4019(13)	
Si-Zn	2.3537(9)	2.3652(12)	
Zn–O	2.095(2)	2.092(3)	
Bond angles			
Cl-Zn-Cl	92.62(3)	91.49(4)	
Zn-Cl-Zn	87.38(3)	88.50(4)	
Si-Si-Si	110.99(av.)	109.22(av.)	

completely recovered. All products were identified by GC, GCMS, and NMR spectra in comparison with those of authentic samples. The yields of products were determined by GC with internal standard methods.

The treatment of **1a** with one molar equivalent of $(Me_3Si)_3GeLi (thf)_3$ under argon atmosphere in diethyl ether at room temperature for 2 h gave bis[(trimethylsilyl)germyl]zinc, [(Me_3Si)_3Ge]_2Zn [7] in 93% isolated yield. One of particular interest is the fact that the redistribution reaction happened on addition of some other organolithium reagents to germylzinc chloride **1a**. The germylzinc chloride **1a** was allowed to react with one molar equivalent of (Me_3Si)_3SiLi (thf)_3 to give not asymmetrically bis(germyl)(silyl)zinc, (Me_3Si)_3GeZn-Si(SiMe_3)_3 but the symmetrical products of [(Me_3Si)_3Ge]_2Zn and [(Me_3Si)_3Si]_2Zn [2b], quntitatively, with the ratio of 1:1. The ratio of redistribution reaction products was determined by the ¹H-NMR signal intensities of Me_3Si groups. The addition of one molar

equivalent of methyllithium, MeLi to 1a led to the formation of [(Me₃Si)₃Ge]₂Zn and Me₂Zn quantitatively with the ratio of 1:1. Expected substitution product (Me₃Si)₃GeZnMe could not be detected at all, probably due to its instability. The formation of Me₂Zn was confirmed by both NMR spectra of authentic sample and chemical trapping experiments with triphenylgermyl chloride, Ph₃GeCl. The reaction mixture of Me₂Zn reacted with Ph₃GeCl to give Ph₃GeMe in 59% yield. Reactions of 1a with one molar equivalent of dimethylphenylsilyllithium, PhMe2SiLi or dimethylphenylgermyllithium, PhMe₂GeLi afforded symmetrical product of [(Me₃Si)₃Ge]₂Zn (50% yield) as a sole product in either case. In the reaction of 1a with silvl- or germyllithium lithium, expected another symmetrical products of (PhMe₂Si)₂Zn or (PhMe₂Ge)₂Zn, respectively, could not be detected under these reaction conditions, probably due to their instability. Of course, unsymmetrical products of (Me₃Si)₃GeZnSiMe₂Ph or (Me₃Si)₃GeZnGeMe₂Ph could not be detected by GC. GCMS, and NMR spectra. The unsymmetrical silyland germyl-substituted zinc are unknown. The reactions of **1a** with electrophiles and organolithiums are summarized in Table 3.

3. Experimental

3.1. General methods

The NMR spectra were obtained on a Varian Unity Inova 400 MHz spectrometer. The GCMS spectra were measured on a JEOL JMS-DX 303 mass spectrometer. Gas chromatography was performed on a Shimadzu GC

Table 3 Reactions of tris(trimethylsilyl)germylzinc chloride (1a) with substrates in diethyl ether

Substrate	Reaction conditions	Products (yield/%)	
H ₂ O	r.t., 6 days	(Me ₃ Si) ₃ GeH (43)	
HC1	r.t., 2 h	(Me ₃ Si) ₃ GeH (100)	
I_2	r.t., 4 days	no reaction	
Me ₃ SiCl	r.t., 4 days	(Me ₃ Si) ₄ Ge (17)	
(Me ₃ Si) ₃ GeLi(thf) ₃	r.t., 2 h	[(Me ₃ Si) ₃ Ge] ₂ Zn (100)	
(Me ₃ Si) ₃ SiLi(thf) ₃	r.t., 2 h	[(Me ₃ Si) ₃ Ge] ₂ Zn (50)	
		$[(Me_{3}Si)_{3}Si]_{2}Zn (50)$	
MeLi	r.t., 2 h	[(Me ₃ Si) ₃ Ge] ₂ Zn (50)	
		Me_2Zn (50)	
PhMe ₂ SiLi	r.t., 2 h	[(Me ₃ Si) ₃ Ge] ₂ Zn (50)	
PhMe ₂ GeLi	r.t., 2 h	[(Me ₃ Si) ₃ Ge] ₂ Zn (50)	

8A with a 1-m 20% SE30 column. X-ray crystallographic data and diffraction intensities were collected on a MacScience DIP2030 diffractiometer utilizing graphite-monochromated Mo-K_{α} ($\lambda = 0.71073$ Å) radiation. The structures were solved by direct methods using the program system SIR-92. A refinement was performed by a SILICON graphics O₂ with MAXUS. THF, diethyl ether, and other solvents were purified and dried as reported in the literature.

3.2. Materials

(Me₃Si)₃SiLi [5], (Me₃Si)₃GeLi [4], PhMe₂GeLi [8], PhMe₂SiLi [8], (Me₃Si)₃GeH [4], (Me₃Si)₄Ge [4], Ph₃GeCl [9], and Ph₃GeMe [10] were prepared as reported in the literature. ZnCl₂, ZnBr₂, ZnI₂, Me₃SiCl, and MeLi are commercially available.

3.3. Structural studies

Germylzinc halides (1a-c) and silylzinc chloride (2a, b) could be obtained in the form crystals suitable for Xray diffraction studies. A single crystal was sealed in a capillary glass tube for the collection. Diffraction data was collected at 200 K on a MacScience DIP2030 image plate diffraction employing graphite-monochromated Mo-K_{α} radiation ($\lambda = 0.71073$ Å). Crystallographic data for 1a-c and 2a,b are listed in Table 4.

3.4. Preparation of tris(trimethylsilyl)germylzinc chloride, (Me₃Si)₃GeZnCl (1a)

 $ZnCl_2$ (0.30 g, 2.17 mmol) reacted with one molar equivalent of $(Me_3Si)_3GeLi(thf)_3$ (1.12 g, 2.17 mmol) containing diethyl ether (10 ml) in Schlenk tube at room temperature (r.t.) for 1 day under argon atmosphere. The concentration of the reaction mixture by removal of diethyl ether followed by addition of pentane (10 ml). The organic layer was filtered. After removal of solvent under vacuum, pentane (3 ml) was added to the residue. The solution was kept at -20 °C. The colorless crystals were filtered off, dried, and shown to be (Me₃-Si)₃GeZnCl(thf) (1a) (0.88 g, 1.87 mmol) in 86% yield. ¹H-NMR (C₆D₆) δ 0.48 (s, 27H), 1.34–1.36 (m, 4H, THF), 3.60–3.62 (m, 4H, THF); ¹³C{¹H}-NMR (C₆D₆) δ 4.7, 25.3 (THF), 68.8 (THF); ²⁹Si{¹H}-NMR (C₆D₆) δ 0.2.

3.5. Preparation of tris(trimethylsilyl)germylzinc bromide, (Me₃Si)₃GeZnBr (1b)

ZnBr₂ (4.05 g, 18.0 mmol) reacted with one molar equivalent of (Me₃Si)₃GeLi(thf)₃ (0.99 g, 1.92 mmol) containing THF (10 ml) in Schlenk tube at r.t. for 3 h under argon atmosphere. The solvent was taken off under reduced pressure. The solid residue was washed twice with pentane (10 ml). The organic layer was filtered. The solvent was concentrated (3 ml), and then kept at -20 °C. Colorless crystals separated, and these were filtered off and judged probably to be (Me₃-Si)₃GeZnBr(thf) (1b) (0.70 g, 1.37 mmol) in 71% yield. ¹H-NMR (C₆D₆) δ 0.46 (s, 27H), 1.34–1.36 (m, 4H, THF), 3.60–3.62 (m, 4H, THF); ¹³C{¹H}-NMR (C₆D₆) δ 4.6, 25.3 (THF), 68.8 (THF); ²⁹Si{¹H}-NMR (C₆D₆) δ –1.0.

3.6. Preparation of tris(trimethylsilyl)germylzinc iodide, (Me₃Si)₃GeZnI (1c)

ZnI₂ (6.00 g, 18.8 mmol) reacted with one molar equivalent of (Me₃Si)₃GeLi(thf)₃ (1.00 g, 1.94 mmol) containing THF (15 ml) in Schlenk tube at r.t. for 3 h under argon atmosphere. The solvent was taken off under reduced pressure. The solid residue was washed twice with pentane (10 ml). The organic layer was filtered. The concentration of the solvent under reduced pressure, and then kept at -20 °C. Colorless crystals separated, and these were filtered off and judged to be (Me₃Si)₃GeZnI(thf) (1c) (0.93 g, 1.67 mmol) in 86% yield. ¹H-NMR (C₆D₆) δ 0.46 (s, 27H), 1.34–1.36 (m, 4H, THF), 3.60–3.62 (m, 4H, THF); ¹³C{¹H}-NMR (C₆D₆) δ 4.7, 25.3 (THF), 68.8 (THF).

3.7. Preparation of tris(trimethylsilyl)silylzinc chloride, (Me₃Si)₃SiZnCl (2a)

ZnCl₂ (5.32 g, 39.0 mmol) reacted with one molar equivalent of $(Me_3Si)_3SiLi(thf)_3$ (1.64 g, 3.48 mmol) containing THF (15 ml) in Schlenk tube at r.t. for 3 h under argon atmosphere. The solvent was taken off under reduced pressure. The solid residue was washed twice with pentane (10 ml). The organic layer was filtered. The solution was concentrated (3 ml), and then kept at -20 °C. Crystals separated, and these were filtered off. Colorless crystals flammable in air with a composition of $(Me_3Si)_3SiZnCl(thf)$ (2a) (1.19 g, 2.83

Table 4	
Crystallographic data for	1a-c, 2a and 2b

	1a	1b	1c	2a	2b
Formula	C13H35ClGeOSi3Zn	C ₁₃ H ₃₅ BrGeOSi ₃ Zn	C ₁₃ H ₃₅ IGeOSi ₃ Zn	C13H35ClOSi4Zn	C ₁₆ H ₃₁ ClOSi ₃ Zn
Mol. wt.	465.09	509.55	556.55	420.59	424.50
Crystal size (mm ³)	$0.25 \times 0.20 \times 0.20$	0.45 imes 0.30 imes 0.30	$0.40 \times 0.40 \times 0.20$	$0.45 \times 0.25 \times 0.25$	$0.40 \times 0.40 \times 0.20$
Crystal system	Monoclinic	Triclinic	Triclinic	Monoclinic	Monoclinic
Space group	$P2_1/n$	P 1	P 1	$P 2_1/n$	$P2_1/c$
Unit cell dimensions					
a (Å)	9.6390(7)	9.5250(5)	9.6080(3)	9.6130(3)	13.7680(10)
b (Å)	20.5050(91)	10.3630(10)	18.1170(10)	20.5070(12)	10.6160(4)
c (Å)	12.7720(9)	13.0280(13)	29.6050(14)	12.6970(8)	17.0490(12)
α (°)	90	92.294(5)	76.118(2)	90	90
β(°)	105.452(3)	105.931(6)	83.763(2)	105.492(4)	113.178
γ (°)	90	96.603(6)	82.980(3)	90	90
V (Å ³)	2433.1(3)	1224.91(18)	4948.4(4)	2412.1(2)	2290.8(2)
Ζ	4	2	2	4	4
Radiation Mo– K_{α} ($\lambda/Å$)	0.71070	0.71070	0.71070	0.71070	0.71070
Temperature (K)	200	200	200	200	200
D_{calc} (g cm ⁻³)	1.270	1.382	1.494	1.158	1.231
Unique reflections	3531	3241	11528	3291	3243
Goodness-of-fit	1.104	1.836	1.817	1.360	1.829
$R \ (I > 2\sigma(I))$	0.0399	0.0559	0.0645	0.0407	0.0541
wR_2	0.1255	0.2069	0.2145	0.1467	0.1994

mmol) were obtained in 81% yield. ¹H-NMR (C₆D₆) δ 0.44 (s, 27H), 1.34–1.36 (m, 4H, THF), 3.60–3.62 (m, 4H, THF); ¹³C{¹H}-NMR (C₆D₆) δ 4.0, 25.3 (THF), 68.8 (THF).

3.8. Preparation of bis(trimethylsilyl)phenylsilylzinc chloride, (Me₃Si)₂PhSiZnCl (**2b**)

ZnCl₂ (5.12 g, 37.6 mmol) reacted with one molar equivalent of Ph(Me₃Si)₂SiLi (4.33 mmol) containing THF (20 ml) in Schlenk tube at r.t. for 1 h under argon atmosphere. The solvent was taken off under reduced pressure. The solid residue was washed twice with pentane (10 ml). The organic layer was filtered, and then removed under reduced pressure. The solid residue was dissolved with pentane (5 ml) and kept at -20 °C. Colorless crystals separated, and these were filtered off and judged probably to be a composition of Ph(Me₃-Si)₂SiZnCl(thf) (**2b**) (1.18 g, 2.44 mmol) in 65% yield. ¹H-NMR (C₆D₆) δ 0.43 (s, 18H), 1.34–1.36 (m, 4H, THF), 3.60–3.62 (m, 4H, THF), 7.09–7.81 (m, 5H); ¹³C{¹H}-NMR (C₆D₆) δ 1.7, 25.3 (THF), 68.8 (THF), 127.1, 127.9, 137.6, 138.7.

3.9. Preparation of bis(trimethylsilyl)phenylsilyllithium

To a THF (5 ml) of bis(trimethylsilyl)phenylsilane, Ph(Me₃Si)₂SiH (1.50 g, 5.9 mmol) in Schlenk tube, pentane solution of *t*-butyllithium (4.3 ml, 6.5 mmol) was introduced by stringe at -40 °C under argon atmosphere. After stirring for 1 h, the reaction mixture was concentrated by evaporation of THF. ¹H-NMR (C₆D₆) δ 0.60 (s, 18H), 1.34–1.36 (m, 12H, THF), 3.60– 3.62 (m, 12H, THF), 7.23 (t, J = 7.0 Hz, 3H), 7.95 (d, J = 3 Hz, 2H); ¹³C{¹H}-NMR (C₆D₆) δ 4.4, 25.3 (THF), 68.8 (THF), 123.5, 126.8, 137.6; ⁷Li-NMR (C₆D₆) δ 0.58.

3.10. Preparation of dimethylzinc

THF- d_8 (7.5 ml) was introduced to a mixture of ZnCl₂ (0.021 g, 0.15 mmol) and MeLi (solid, 0.029 g, 0.30 mmol) in NMR tube, at low temperature under argon atmosphere. The reaction mixture was allowed to r.t. and stirred for 5 min. ¹H-NMR (THF- d_8) δ -1.44 (s, 9H).

3.11. Hydrolysis of tris(trimethylsilyl)germylzinc chloride (1a) with water

A diethyl ether solution (10 ml) of **1a** (1.00 mmol), excess amount of deoxygenated H₂O, and nonadecane as internal standard under argon atmosphere was stirred at r.t. for 6 days in Schlenk tube. Tris(trimethylsilyl)germane, (Me₃Si)₃GeH (0.43 mmol) was formed in 43% GC yield. Unreacted **1a** (0.50 mmol) was recovered. (Me₃Si)₃GeH: ¹H-NMR (C₆D₆) δ 0.28 (s, 27H), 2.16 (s, 1H); ¹³C{¹H}-NMR (C₆D₆) δ 3.4. GCMS *m*/*z* 294 ([*M*]⁺, 20), 278 (5), 220 (40), 146 (35), 131 (40), 73 (100).

3.12. Hydrolysis of tris(trimethylsilyl)germylzinc chloride (1a) with hydrochloric acid

A diethyl ether solution (10 ml) of **1a** (1.00 mmol), excess amount of conc. HCl, and nonadecane as internal standard under argon atmosphere was stirred at r.t. for

2 h in Schlenk tube. Tris(trimethylsilyl)germane, (Me₃-Si)₃GeH (0.95 mmol) was formed in 95% GC yield.

3.13. Reaction of tris(trimethylsilyl)germylzinc chloride (1a) with trimethylchlorosilane

A diethyl ether solution (10 ml) of **1a** (1.00 mmol), excess amount of Me₃SiCl, and nonadecane as internal standard was stirred at r.t. for 4 days in Schlenk tube under argon atmosphere. Tetrakis(trimethylsilyl)germane, (Me₃Si)₄Ge (0.17 mmol) was formed in 17% GC yield. Unreacted **1a** (0.80 mmol) was recovered. (Me₃-Si)₄Ge: ¹H-NMR (C₆D₆) δ 0.30 (s, 36H; ¹³C{¹H}-NMR (C₆D₆) δ 3.5. GCMS *m*/*z* 366 ([*M*]⁺ 30), 351 (20), 293 (10), 278 (100), 219 (20), 205 (15), 187 (20), 144 (10), 131 (25), 73 (90).

3.14. Reaction of tris(trimethylsilyl)germylzinc chloride (1a) with tris(trimethylsilyl)germyllithium

(Me₃Si)₃GeLi(thf)₃ (0.34 mmol) in THF (10 ml) was added to a THF solution (5 ml) of **1a** (0.34 mmol) in a Schlenk tube, under argon atmosphere. The reaction mixture was stirred at r.t. for 2 h. bis[Tris(trimethylsilyl)germyl]zinc, [(Me₃Si)₃Ge]₂Zn (0.34 mmol) was formed quantitatively. [(Me₃Si)₃Ge]₂Zn: ¹H-NMR (C₆D₆) δ 0.39 (s, 54H); ¹³C{¹H}-NMR (C₆D₆) δ 5.2; ²⁹Si{¹H}-NMR δ -2.3.

3.15. Reaction of tris(trimethylsilyl)germylzinc chloride (1a) with tris(trimethylsilyl)silyllithium

(Me₃Si)₃SiLi(thf)₃ (0.34 mmol) in THF (10 ml) was added to a THF solution (5 ml) of **1a** (0.34 mmol) in a Schlenk tube, under argon atmosphere. The reaction mixture was stirred at r.t. for 2 h. [(Me₃Si)₃Ge]₂Zn (0.17mmol) and bis[tris(trimethylsily])sily]]zinc, [(Me₃-Si)₃Si]₂Zn (0.17 mmol) were formed with the ratio of 1:1 in quantitatively. [(Me₃Si)₃Si]₂Zn: ¹H-NMR (C₆D₆) δ 0.35 (s, 54H); ¹³C{¹H}-NMR (C₆D₆) δ 4.5.

3.16. Reaction of tris(trimethylsilyl)germylzinc chloride (1a) with methyllithium

MeLi (0.47 mmol) in THF (25 ml) was added to a THF solution (5 ml) of **1a** (0.45 mmol) in a Schlenk tube, methyllithium, under argon atmosphere. The reaction mixture was stirred at r.t. for 1.5 h. [(Me₃-Si)₃Ge]₂Zn (0.23 mmol) was formed. Dimethylzinc, Me₂Zn was confirmed by NMR analysis. Me₂Zn: ¹H-NMR (THF- d_8) δ -1.42 (s, 9H).

3.17. Reaction of tris(trimethylsilyl)germylzinc chloride (1a) with phenyldimethylgermyllithium

PhMe₂GeLi (0.69 mmol) in THF (6 ml) was added to a THF solution (5 ml) of **1a** (0.69 mmol), phenyldimethylgermyllithium in a Schlenk tube, under argon atmosphere. The reaction mixture was stirred at r.t. for 1.5 h. [(Me₃Si)₃Ge]₂Zn (0.35 mmol) was formed.

3.18. Reaction of tris(trimethylsilyl)germylzinc chloride (1a) with phenyldimethylsilyllithium

PhMe₂SiLi (0.69 mmol) in THF (6 ml) was added to a THF solution (5 ml) of **1a** (0.69 mmol), phenyldimethylsilyllithium in a Schlenk tube, under argon atmosphere. The reaction mixture was stirred at r.t. for 1.5 h. $[(Me_3Si)_3Ge]_2Zn$ (0.35 mmol) was formed.

3.19. Reaction of dimethylzinc with triphenylgermyl chloride

MeLi (0.43 mmol) in THF (4 ml) was added to a THF solution (5 ml) of **1a** (0.43 mmol) in a Schlenk tube, under argon atmosphere. The reaction mixture was stirred at r.t. for 1.5 h. To a triphenylchlorogermane, Ph₃GeCl (0.58 mmol) in a Schlenk tube, the THF solution of Me₂Zn was transferred by means of vacuum line. The reaction mixture was stirred at r.t. for 1 day. Triphenylmethylgermane, Ph₃GeMe was formed in 59% yield.

4. Supplementary material

Crystallographic data for the structural analysis have been deposited with the Cambridge Crystallographic Data Centre, CCDC nos. 194958–194962 for compounds **1a–c** and **2a,b**, respectively. Copies of this information may be obtained free of charge from The Director, CCDC, 12 Union Road, Cambridge CB2 1EZ, UK (Fax: +44-1223-336033; e-mail: deposit@ccdc.cam. ac.uk or www: http://www.ccdc.cam.ac.uk).

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